

03-07-01

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IN THE UNITED STATES  
PATENT AND TRADEMARK OFFICE

## PATENT APPLICATION

By Express Mail - Label No. EK 976 499 625 US

**INVENTOR** John Howard Coleman,  
40 Overlook Road, Locust Valley, NY 11560

**TITLE** Semiconductor Fabrication and Structure for  
Field-Effect and Bipolar Transistor Devices

**ASSISTANT COMMISSIONER FOR PATENTS**  
WASHINGTON, D.C. 20231

**SIR:**

Enclosed are the following papers relating to the above-named application for patent:

15 pages of Specification with Claims and Abstract  
3 sheets of Drawing(s)  
2 pages of Declaration and Power of Attorney

## CLAIMS AS FILED

	FILED	EXTRA	RATE	CALCULATIONS
Total Claims	21 - 20 =	1	× \$ 9 =	\$ 9
Independent Claims	3 - 3 =	0	× \$40 =	
Basic Fee				<u>\$355</u>
			TOTAL	\$364

The applicant qualifies for Small-Entity status.

The applicant claims priority based on his provisional application No. 60/187,290 filed March 6, 2000, entitled Method of Making New Semiconductor Material for Field Effect Transistors by Hydrogen Ion Implantation.

Please file the application and charge the applicant's **Deposit Account No. 16-2080** the amount of \$364.00, to cover the filing fee. A copy of this letter is enclosed. In the event of non-payment or improper payment of a required fee, the Commissioner is authorized to charge or credit **Deposit Account No. 16-2080** as required to correct the error.

Please address all correspondence to **Peter A. Businger, Esq., 344 Valleyscent Avenue, Scotch Plains, NJ 07076-1170**, telephone (908) 322-4835.

Respectfully,

*Peter A. Businger*  
Peter A. Businger  
Reg. No. 27,862  
Attorney for Applicant(s)

Date: March 6, 2001

JC997 U.S. PTO  
09/800213  
03/06/01